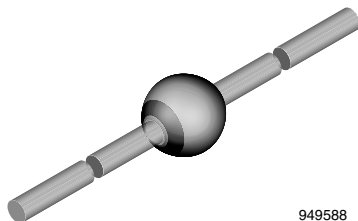




Standard Avalanche Sinterglass Diode



FEATURES

- Glass passivated junction
- Hermetically sealed package
- Controlled avalanche characteristics
- Low reverse current
- High surge current loading
- Material categorization:
For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

MECHANICAL DATA

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

Mounting position: any

Weight: approx. 858 mg

APPLICATIONS

- Rectification diode, general purpose

ORDERING INFORMATION (Example)

| DEVICE NAME | ORDERING CODE | TAPED UNITS | MINIMUM ORDER QUANTITY |
|-------------|---------------|----------------------------|------------------------|
| 1N5627 | 1N5627-TR | 2500 per 10" tape and reel | 12 500 |
| 1N5627 | 1N5627-TAP | 2500 per ammpack | 12 500 |

PARTS TABLE

| PART | TYPE DIFFERENTIATION | PACKAGE |
|--------|---|---------|
| 1N5624 | $V_R = 200\text{ V}$; $I_{F(AV)} = 3\text{ A}$ | SOD-64 |
| 1N5625 | $V_R = 400\text{ V}$; $I_{F(AV)} = 3\text{ A}$ | SOD-64 |
| 1N5626 | $V_R = 600\text{ V}$; $I_{F(AV)} = 3\text{ A}$ | SOD-64 |
| 1N5627 | $V_R = 800\text{ V}$; $I_{F(AV)} = 3\text{ A}$ | SOD-64 |

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ °C}$, unless otherwise specified)

| PARAMETER | TEST CONDITION | PART | SYMBOL | VALUE | UNIT |
|--|---|--------|-----------------|---------------|----------------------|
| Reverse voltage = repetitive peak reverse voltage | See electrical characteristics | 1N5624 | $V_R = V_{RRM}$ | 200 | V |
| | | 1N5625 | $V_R = V_{RRM}$ | 400 | V |
| | | 1N5626 | $V_R = V_{RRM}$ | 600 | V |
| | | 1N5627 | $V_R = V_{RRM}$ | 800 | V |
| Peak forward surge current | $t_p = 10\text{ ms}$, half sinewave | | I_{FSM} | 100 | A |
| Repetitive peak forward current | | | I_{FRM} | 18 | A |
| Average forward current | | | $I_{F(AV)}$ | 3 | A |
| Pulse avalanche peak power | $t_p = 20\text{ }\mu\text{s}$, half sine wave, $T_j = 175\text{ °C}$ | | P_R | 1000 | W |
| Pulse energy in avalanche mode, non repetitive (inductive load switch off) | $I_{(BR)R} = 1\text{ A}$, $T_j = 175\text{ °C}$ | | E_R | 20 | mJ |
| i^2t -rating | | | i^2t | 40 | A^2s |
| Junction and storage temperature range | | | $T_j = T_{stg}$ | - 55 to + 175 | $^{\circ}\text{C}$ |

MAXIMUM THERMAL RESISTANCE ($T_{amb} = 25\text{ °C}$, unless otherwise specified)

| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
|------------------|--|------------|-------|------|
| Junction ambient | $l = 10\text{ mm}$, $T_L = \text{constant}$ | R_{thJA} | 25 | K/W |
| | On PC board with spacing 25 mm | R_{thJA} | 70 | K/W |

| ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | | |
|--|--|------|------------|------|------|------|---------------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 3\text{ A}$ | | V_F | - | - | 1 | V |
| Reverse current | $V_R = V_{RRM}$ | | I_R | - | 0.1 | 1 | μA |
| | $V_R = V_{RRM}, T_j = 100\text{ }^{\circ}\text{C}$ | | I_R | - | 5 | 10 | μA |
| Breakdown voltage | $I_R = 100\text{ }\mu\text{A}, t_p/T = 0.01,$ $t_p = 0.3\text{ ms}$ | | $V_{(BR)}$ | - | - | 1600 | V |
| Diode capacitance | $V_R = 4\text{ V}, f = 1\text{ MHz}$ | | C_D | - | 40 | 60 | pF |
| Reverse recovery time | $I_F = 0.5\text{ A}, I_R = 1\text{ A}, i_R = 0.25\text{ A}$ | | t_{rr} | - | 3.5 | 5 | μs |
| | $I_F = 1\text{ A}, dI/dt = 5\text{ A}/\mu\text{s}, V_R = 50\text{ V}$ | | t_{rr} | - | 4.5 | 7.5 | μs |
| Reverse recovery charge | $I_F = 1\text{ A}, dI/dt = 5\text{ A}/\mu\text{s}$ | | Q_{rr} | - | 8 | 12 | μC |

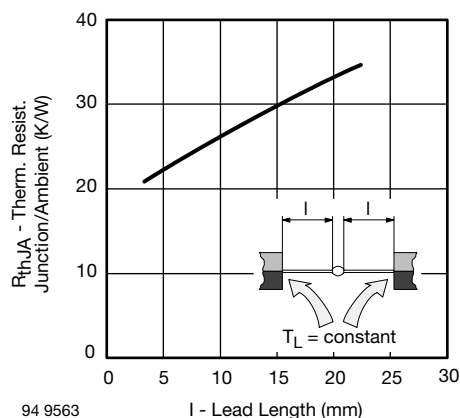
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 1 - Max. Thermal Resistance vs. Lead Length

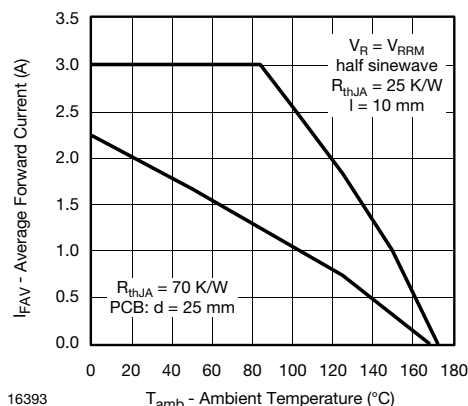


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

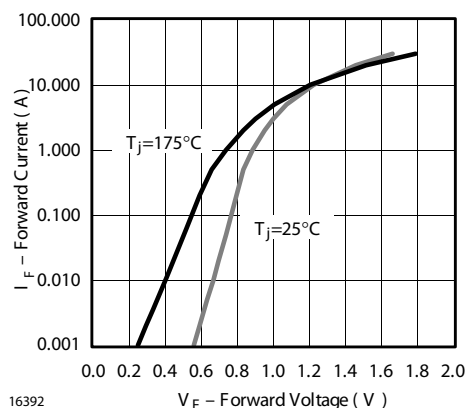


Fig. 2 - Forward Current vs. Forward Voltage

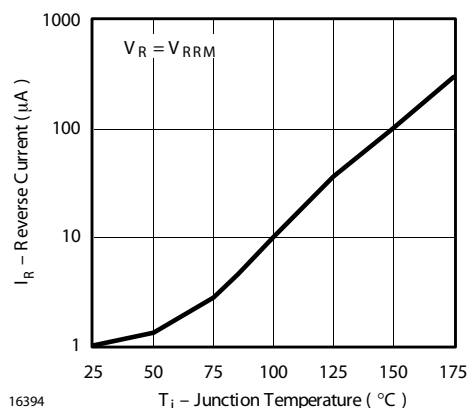


Fig. 4 - Reverse Current vs. Junction Temperature

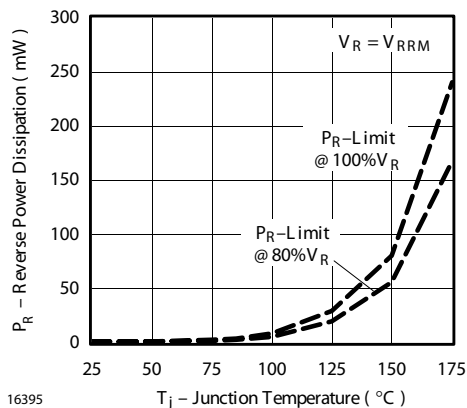


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

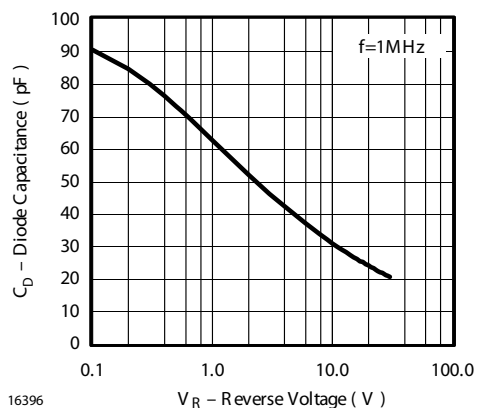
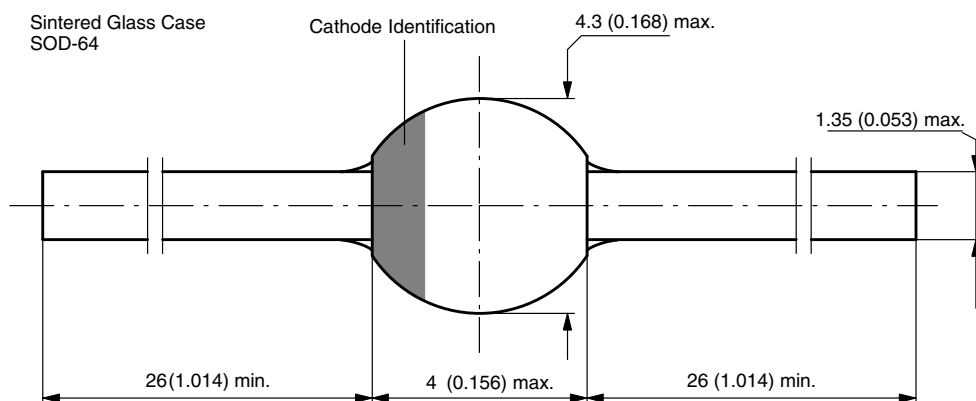


Fig. 6 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): SOD-64



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